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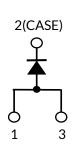






# **UJ3D1250K**





# Silicon Carbide (SiC) Diode - EliteSiC, TO-247-3L, 50 A, 1200 V SiC Merged PiN-Schottky (MPS) Diode

Rev. E, Jan 2025

#### Description

UnitedSiC offers the  $3^{rd}$  generation of high performance SiC Merged-PiN-Schottky (MPS) diodes. With zero reverse recovery charge and  $175^{\circ}$ C maximum junction temperature, these diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.

#### **Features**

- Maximum operating temperature of 175°C
- Easy paralleling
- Extremely fast switching not dependent on temperature
- No reverse or forward recovery
- Enhanced surge current capability, MPS structure
- 100% UIS tested
- AEC-Q101 qualified
- AECQ Qualified

Part Number	Package	Marking
UJ3D1250K	TO-247-3L	UJ3D1250K







#### **Typical applications**

- Power converters
- Industrial motor drives
- Switch mode power supplies
- Power factor correction modules













## Maximum Ratings

Parameter	Symbol	<b>Test Conditions</b>	Value	Units	
DC blocking voltage	$V_R$		1200	V	
Repetitive peak reverse voltage, T <sub>J</sub> =25°C	$V_{RRM}$		1200	V	
Surge peak reverse voltage	$V_{RSM}$		1200	V	
Maximum DC forward current	I <sub>F</sub>	T <sub>C</sub> = 112°C	50	Α	
Non-repetitive forward surge current sine halfwave	I <sub>FSM</sub>	$T_C = 25^{\circ}C, t_p = 10 \text{ms}$	275	А	
Repetitive forward surge current		$T_C = 25^{\circ}C$ , $t_p = 10 \text{ms}$	163.5	۸	
sine halfwave, D=0.1	I <sub>FRM</sub>	$T_C = 110^{\circ}C, t_p = 10 \text{ms}$	99.6	Α	
Non-repetitive peak forward current	I <sub>F,max</sub> -	$T_C = 25^{\circ}C, t_p = 10 \mu s$	2400		
		$T_C = 110$ °C, $t_p = 10 \mu s$	2400	Α	
i <sup>2</sup> t value	∫i²dt	$T_C = 25^{\circ}C, t_p = 10 \text{ms}$	378	$A^2s$	
Power dissipation	P <sub>tot</sub> -	T <sub>C</sub> = 25°C	319	W	
		T <sub>C</sub> = 112°C	134		
Maximum junction temperature	$T_{J,max}$		175	°C	
Operating and storage temperature	$T_J,T_STG$		-55 to 175	°C	
Soldering temperatures, wavesoldering only allowed at leads	$T_{sold}$	1.6mm from case for 10s	260	°C	

#### **Thermal Characteristics**

Doramotor	Symbol	Test Conditions	Value			Units
Parameter			Min	Тур	Max	Units
Thermal resistance, junction-to-case	$R_{\theta IC}$			0.36	0.47	°C/W

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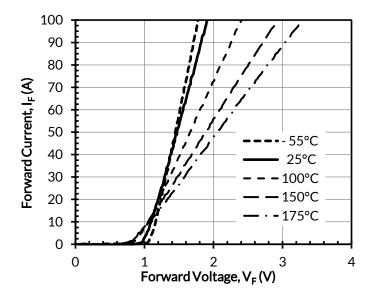


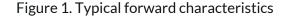
# Electrical Characteristics (T<sub>J</sub> = +25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Value			Limita
			Min	Тур	Max	- Units
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 50A, T <sub>J</sub> =25°C	-	1.5	1.7	V
		I <sub>F</sub> = 50A, T <sub>J</sub> =150°C	-	1.95	2.4	
		I <sub>F</sub> = 50A, T <sub>J</sub> =175°C	-	2.2	2.7	
Reverse current	I <sub>R</sub>	V <sub>R</sub> =1200V, T <sub>J</sub> =25°C	-	52	400	μΑ
		V <sub>R</sub> =1200V, T <sub>J</sub> =175°C	-	900		
Total capacitive charge <sup>(1)</sup>	Q <sub>C</sub>	V <sub>R</sub> =800V		240		nC
Total capacitance	С	$V_R=1V, f=1MHz$		2340		pF
		V <sub>R</sub> =400V, f = 1MHz		224		
		V <sub>R</sub> =800V, f = 1MHz		198		
Capacitance stored energy	E <sub>C</sub>	V <sub>R</sub> =800V		72		μЈ

(1)  $Q_c$  is independent on  $T_J$ ,  $di_F/dt$ , and  $I_F$  as shown in the application note USCi\_AN0011.

#### **Typical Performance Diagrams**





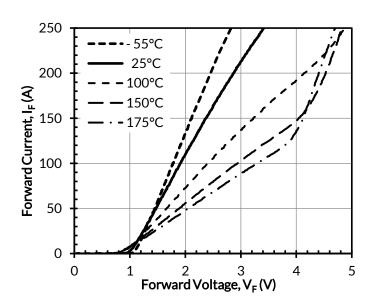


Figure 2. Typical forward characteristics in surge current



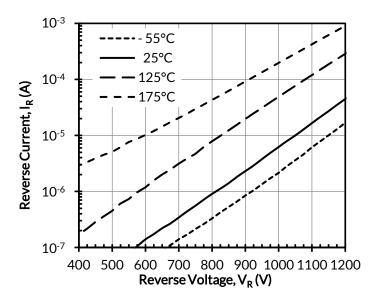








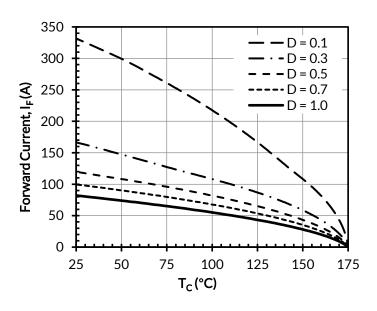




Power Disspiation, P<sub>Tot</sub> (W) T<sub>C</sub> (°C)

Figure 3. Typical reverse characteristics

Figure 4. Power dissipation



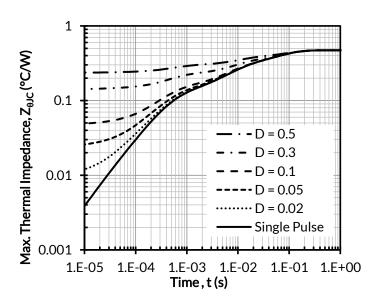


Figure 5. Diode forward current

Figure 6. Maximum transient thermal impedance



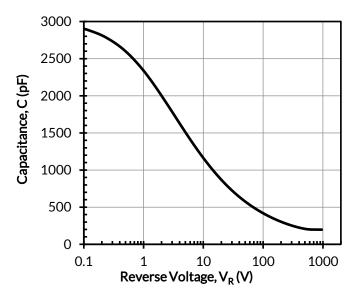












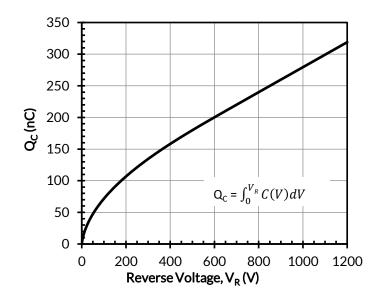


Figure 7. Capacitance vs. reverse voltage at 1MHz

Figure 8. Typical capacitive charge vs. reverse voltage

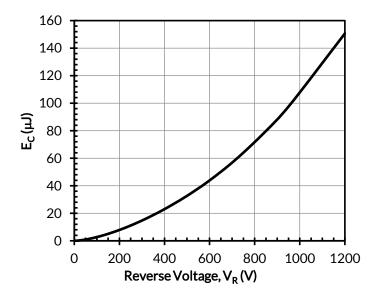


Figure 9. Typical capacitance stored energy vs. reverse voltage

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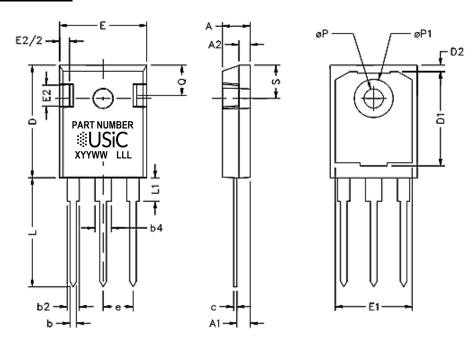
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# TO-247-3L PACKAGE OUTLINE, PART MARKING AND TUBE SPECIFICATIONS

### **PACKAGE OUTLINE**

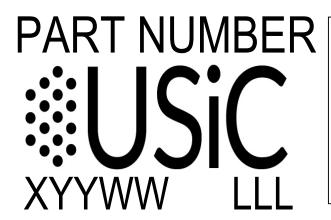


SYM	INCHES		MILLIMETERS		
	MIN	MAX	MIN	MAX	
Α	0.185	0.209	4.699	5.309	
A1	0.087	0.102	2.21	2.61	
A2	0.059	0.098	1.499	2.489	
b	0.039	0.055	0.991	1.397	
b2	0.065	0.094	1.651	2.388	
b4	0.102	0.135	2.591	3.429	
С	0.015	0.035	0.381	0.889	
D	0.819	0.845	20.803	21.463	
D1	0.515	-	13.081	-	
D2	0.02	0.053	0.508	1.346	
E	0.61	0.64	15.494	16.256	
е	0.214	4 BSC	5.44 BSC		
E1	0.53	-	13.462	-	
E2	0.135	0.157	3.429	3.988	
L	0.78	0.8	19.812	20.32	
L1	ı	0.177	ī	4.496	
ØΡ	0.14	0.144	3.556	3.658	
ØP1	0.278	0.291	7.061	7.391	
Q	0.212	0.244	5.385	6.198	
S	0.243	3 BSC	6.17 BSC		



# TO-247-3L PACKAGE OUTLINE, PART MARKING AND TUBE SPECIFICATIONS

#### **PART MARKING**



PART NUMBER = REFER TO
DS PN DECODER FOR DETAILS

X = ASSEMBLY SITE

YY = YEAR

WW = WORK WEEK

LLL = LOT ID

#### **PACKING TYPE**

**ANTI-STATIC TUBE** 

**QUANTITY /TUBE: 30 UNITS** 

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